

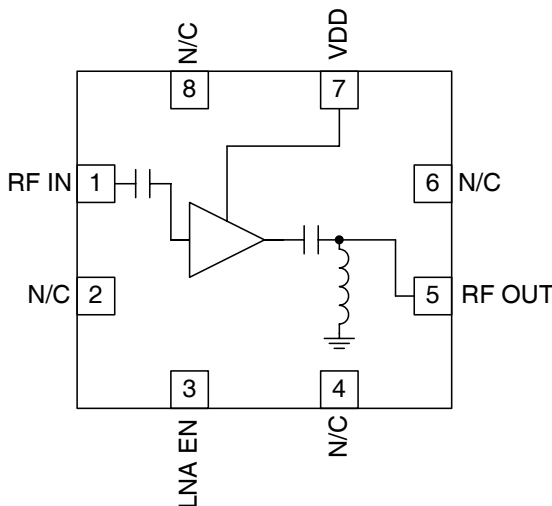


**Features**

- 4.9GHz to 5.85GHz Operation
- 2.3V to 4.8V Single Supply
- 1.6dB Noise Figure
- 11dB Typical Gain

**Applications**

- High Band WLAN LNA/Driver
- General Purpose Amplifier for Portable Applications



Functional Block Diagram

**Product Description**

The RF5515 is a high performance Low Noise Amplifier design for 802.11a applications (4.9GHz to 5.85GHz) and other portable consumer electronics. This miniature LNA features a high dynamic range and high intercept point with low current consumption around 12mA. The LNA is DC blocked and internally matched to 50Ω at input and output pins. The IC is featured in a 2.2mmx2.2mmx0.5mm module compatible plastic package.

**Ordering Information**

- RF5515                      4.9GHz to 5.85GHz Low Noise Amplifier with Enable (Sn-Pb finish)
- RF5515 PCBA-410      Fully Assembled Evaluation Board, 5GHz

**Optimum Technology Matching® Applied**

- |                                      |                                      |  |                                   |
|--------------------------------------|--------------------------------------|--|-----------------------------------|
| <input type="checkbox"/> GaAs HBT    | <input type="checkbox"/> SiGe BiCMOS | <input checked="" type="checkbox"/> GaAs pHEMT | <input type="checkbox"/> GaN HEMT |
| <input type="checkbox"/> GaAs MESFET | <input type="checkbox"/> Si BiCMOS   | <input type="checkbox"/> Si CMOS               | <input type="checkbox"/> RF MEMS  |
| <input type="checkbox"/> InGaP HBT   | <input type="checkbox"/> SiGe HBT    | <input type="checkbox"/> Si BJT                | <input type="checkbox"/> LDMOS    |

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## Absolute Maximum Ratings

Parameter	Rating	Unit
DC Supply Voltage	5.5	V
Maximum Input Power (No Damage)	10	dBm
Operating Temperature	-15 to +75	°C
Extreme Operating Temperature	-40 to -15	°C
	+75 to +85	°C
Storage Temperature	-40 to +150	°C



**Caution!** ESD sensitive device.

Exceeding any one or a combination of the Absolute Maximum Rating conditions may cause permanent damage to the device. Extended application of Absolute Maximum Rating conditions to the device may reduce device reliability. Specified typical performance or functional operation of the device under Absolute Maximum Rating conditions is not implied.

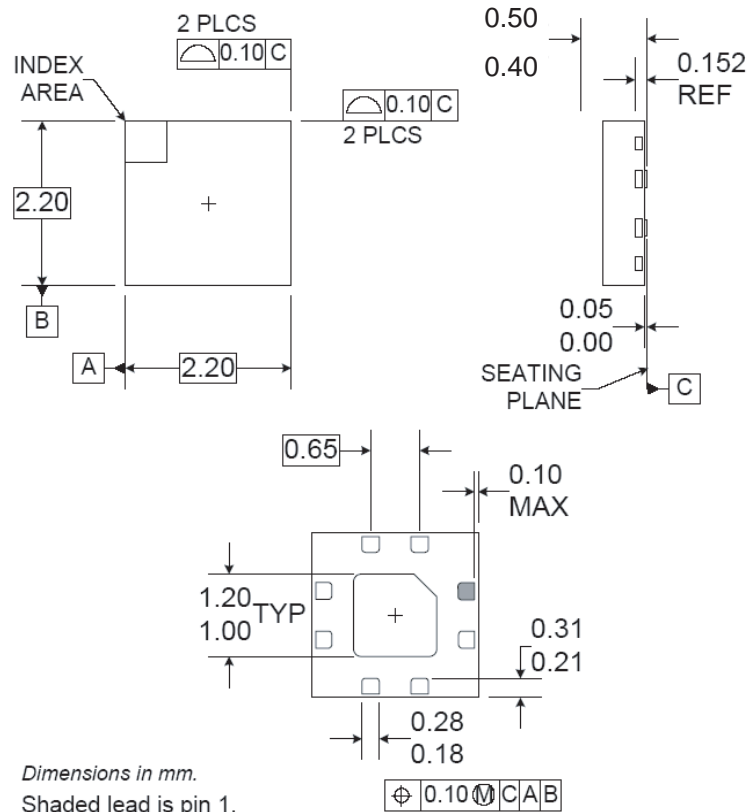
RoHS status based on EU Directive 2002/95/EC (at time of this document revision).

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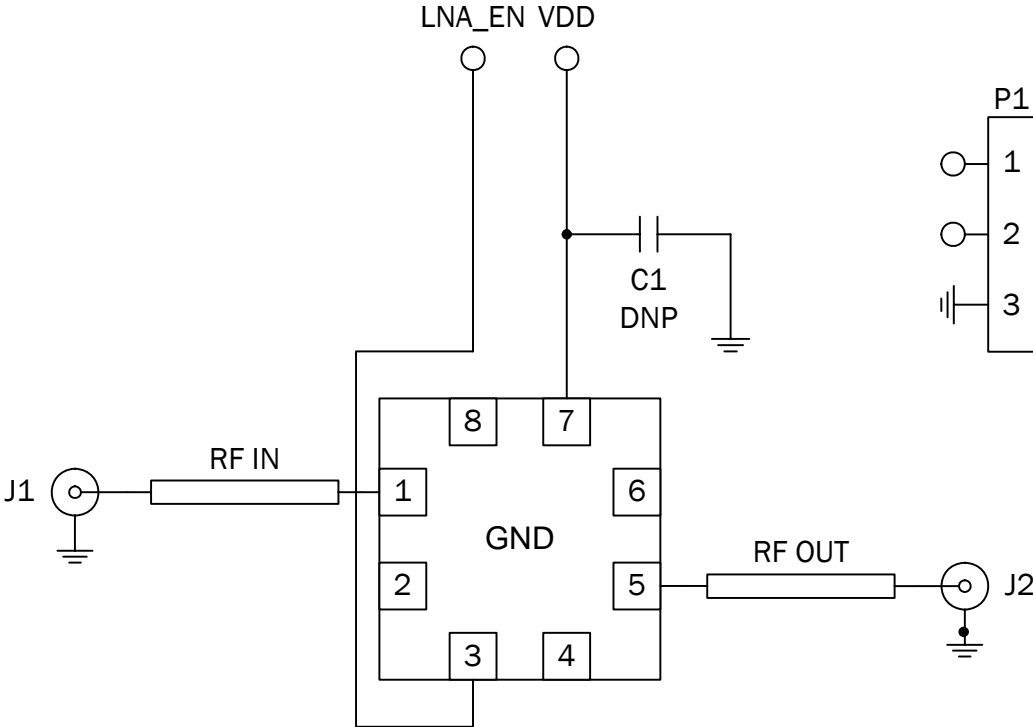
Parameter	Specification			Unit	Condition
	Min.	Typ.	Max.		
<b>Typical Conditions</b>					Temp=25 °C, V <sub>DD</sub> =3.3V, LNA_EN=3.3V, Frequency=4.9GHz to 5.85GHz unless otherwise noted in the condition column.
Frequency	4.9		5.85	GHz	
LNA Voltage Supply (V <sub>DD</sub> )	2.7	3.3	4.8	V	
LNA Enable Voltage (LNA_EN)	2.5		4.8	V <sub>DD</sub>	LNA Enabled
		0	0.2	V	LNA Off
LNA Current					
LNA V <sub>DD</sub>		12	20	mA	LNA in "On" state, over operating temperature range, Full V <sub>DD</sub> range, full LNA_EN range, and full frequency band.
	0		5	µA	LNA in "Off" state
LNA Enable			200	µA	
Gain					
WLAN RX Only	9	11	13	dB	WLAN RX Mode, Over full operating temperature range, full V <sub>CC</sub> range, Full LNA_EN range, and full frequency range.
		TBD		dB	WLAN RX Mode LNA "Off", V <sub>DD</sub> =3.3V and LNA_EN=0V.
Noise Figure					
WLAN RX		1.7	2.2	dB	WLAN RX Mode, Over Full V <sub>DD</sub> range, full LNA_EN range, Full frequency range, and over operating temperature range.
Passband Ripple	-0.5		+0.5	dB	WLAN RX Mode
Input P1dB	-4	-1		dBm	Over operating temperature range, full voltage range, full LNA_EN range, and full frequency range.
WLAN RX Port Return Loss			-9.6	dB	4.9GHz to 5.85GHz
WLAN RX Port Impedance		50		Ω	No external matching

Pin	Function	Description
1	RF IN	RF Input. Input is matched to 50Ω and DC block is provided internally.
2	NC	No Connect
3	LNA_EN	LNA Enable. Voltage whihc is a high impedance pin could require bypassing depending on the nature of the supply voltage and the layout.
4	NC	No Connect
5	RF OUT	RF Output. This pin is matched to 50Ω internally and it is a DC short to GND. See functional block diagram for more details.
6	NC	No Connect
7	VDD	Supply Voltage for the LNA circuit. It is recommended that bypass capacitors are placed on this voltage line as needed depending on the nature of the supply voltage and layout.
8	NC	No Connect
Pkg Base	GND	The center metal base of the QFN package provides DC and RF ground as well as heat sink for the amplifier.

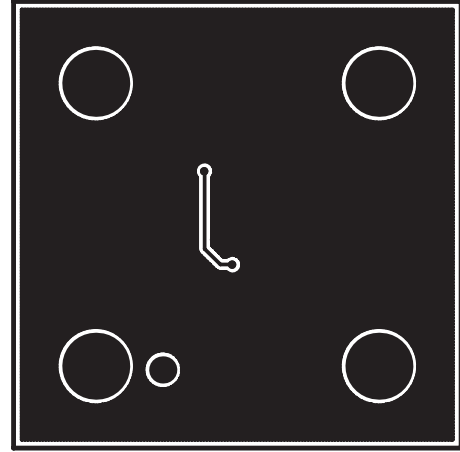
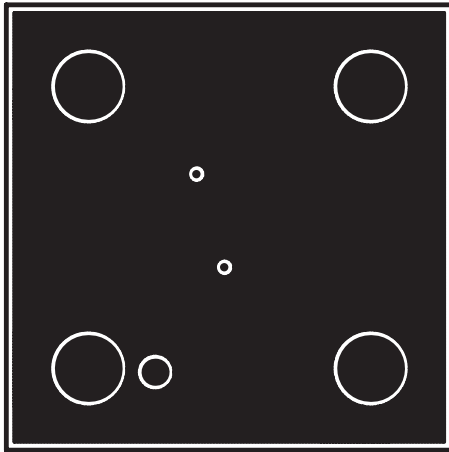
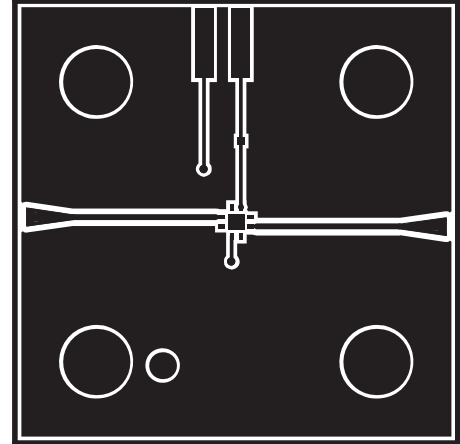
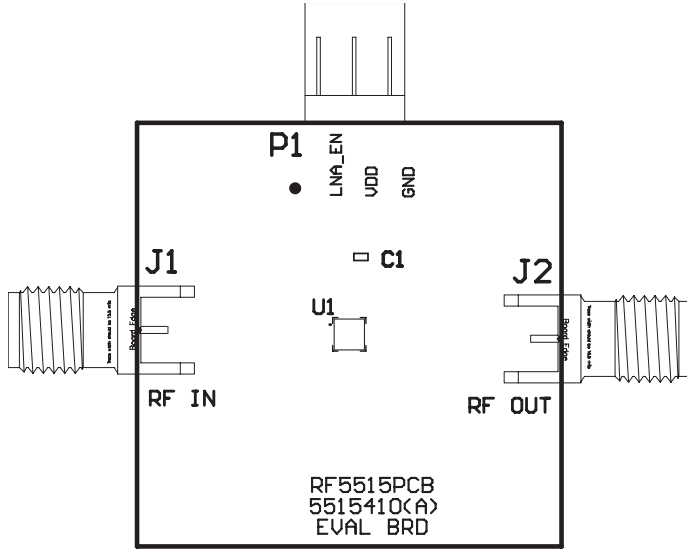
**Package Drawing**  
2.2mmx2.2mmx0.5mm



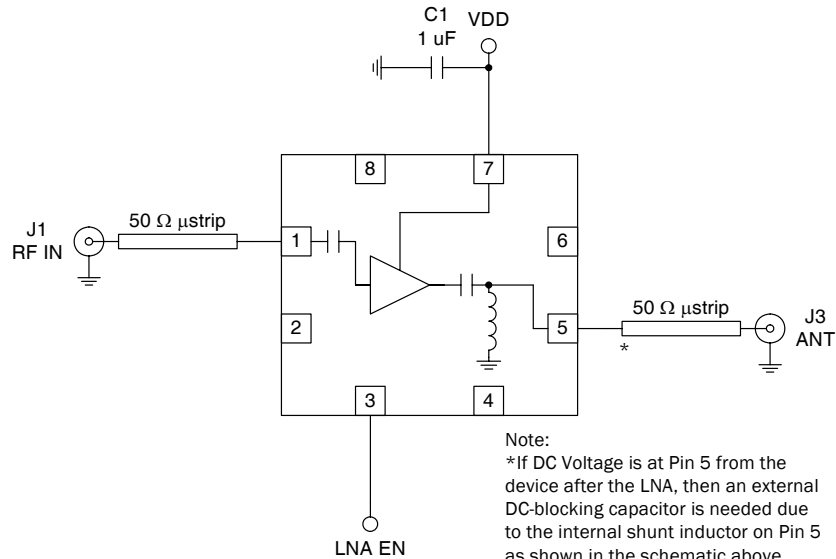
## Evaluation Board Schematic



**Evaluation Board Layout**

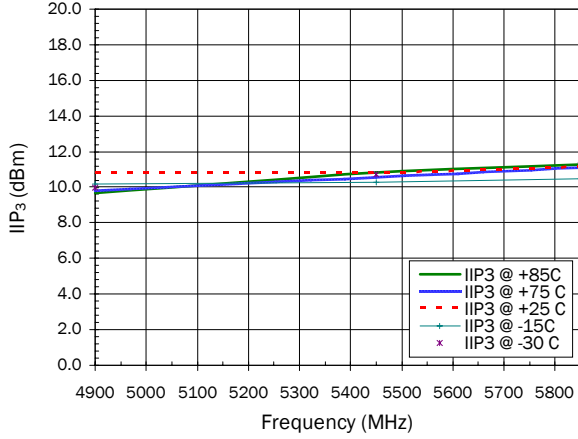


## Application Schematic - 4.9GHz to 5.85GHz

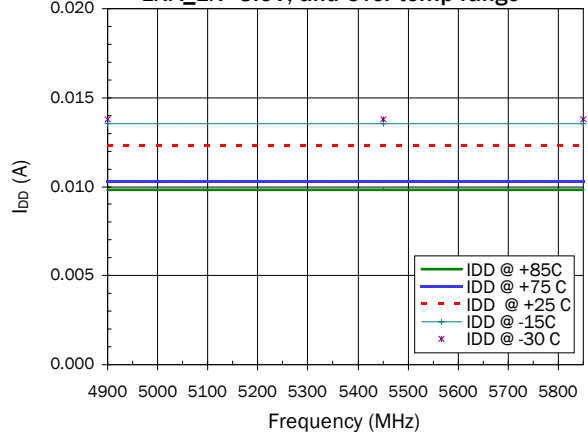


Note:  
 \*If DC Voltage is at Pin 5 from the device after the LNA, then an external DC-blocking capacitor is needed due to the internal shunt inductor on Pin 5 as shown in the schematic above.  
 \*\* On the evaluation board adding C1, which is 1 uF, did not make any difference but could be needed depending on the layout and the nature of the supply voltage used in the system.

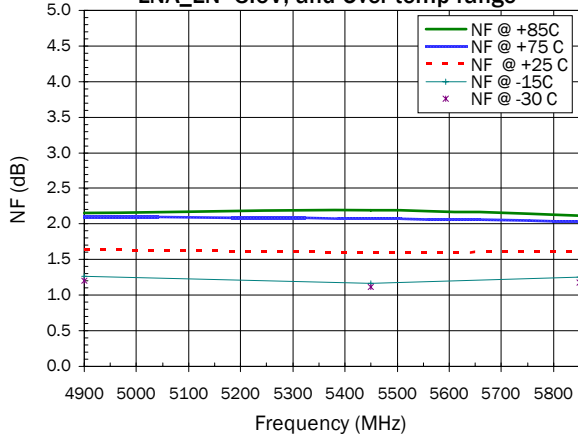
Typical IIP<sub>3</sub> versus Frequency V<sub>DD</sub>=3.0, LNA\_EN=3.0V, and Over temp range



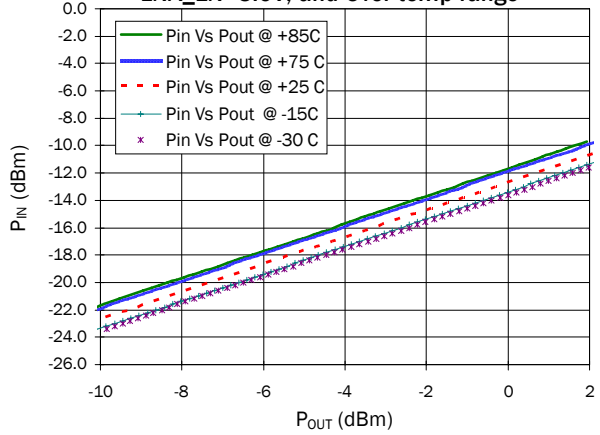
Typical I<sub>DD</sub> versus Frequency V<sub>DD</sub>=3.0, LNA\_EN=3.0V, and Over temp range



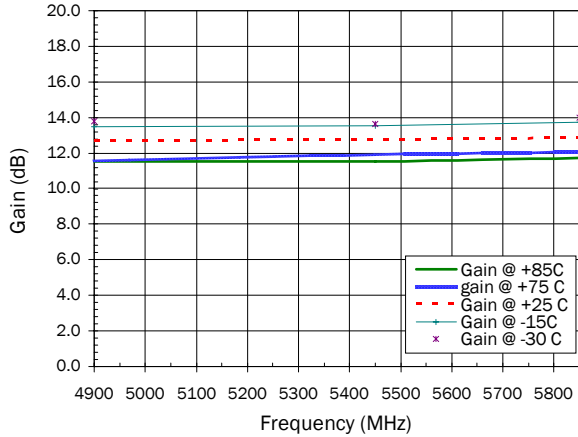
Typical NF versus Frequency V<sub>DD</sub>=3.0, LNA\_EN=3.0V, and Over temp range



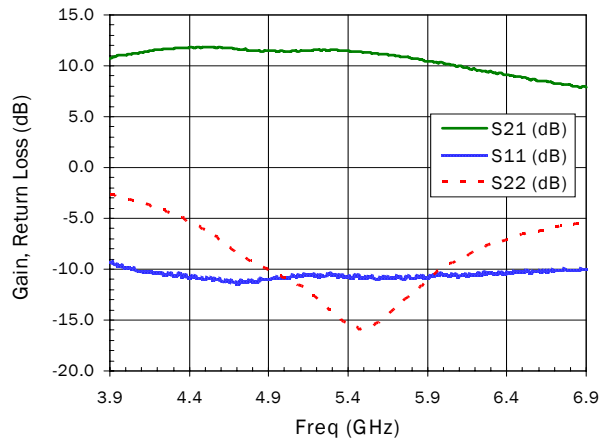
Typical P<sub>IN</sub> versus P<sub>OUT</sub> at 5.45 GHz at V<sub>DD</sub>=3.0, LNA\_EN=3.0V, and Over temp range



Typical Gain versus Frequency V<sub>DD</sub>=3.0, LNA\_EN=3.0V, at Pin -25 dBm, and Over temp range



Typical S-Plots at V<sub>DD</sub>=3.0, LNA\_EN=3.0V



# RF5515



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RFMD Technical Support  
at (336) 678-5570  
for more information.**